

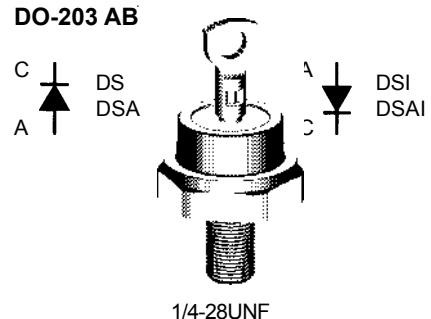
# Rectifier Diode

## Avalanche Diode

**V<sub>RRM</sub> = 800-1800 V**  
**I<sub>F(RMS)</sub> = 160 A**  
**I<sub>F(AV)M</sub> = 110 A**

V <sub>RSM</sub> V	V <sub>(BR)min</sub> V	V <sub>RRM</sub> V	Anode on stud	Cathode on stud
900	-	800	DS 75-08B	DSI 75-08B
1300	-	1200	DS 75-12B	DSI 75-12B
1300	1300	1200	DSA 75-12B	DSAI 75-12B
1700	1760	1600	DSA 75-16B	DSAI 75-16B
1900	1950	1800	DSA 75-18B	DSAI 75-18B

① Only for Avalanche Diodes

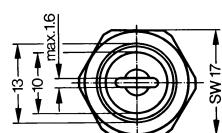
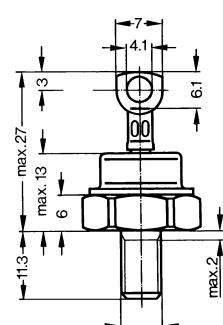


A = Anode    C = Cathode

Symbol	Test Conditions	Maximum Ratings		
I <sub>F(RMS)</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	160	A	
I <sub>F(AV)M</sub>	T <sub>case</sub> = 100°C; 180° sine	110	A	
P <sub>RSM</sub>	DSA(I) types, T <sub>VJ</sub> = T <sub>VJM</sub> , t <sub>p</sub> = 10 µs	20	kW	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine	1400	A	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz), sine	1500	A	
	T <sub>VJ</sub> = T <sub>VJM</sub> t = 10 ms (50 Hz), sine	1250	A	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz), sine	1310	A	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C t = 10 ms (50 Hz), sine	9800	A <sup>2</sup> s	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz), sine	9450	A <sup>2</sup> s	
	T <sub>VJ</sub> = T <sub>VJM</sub> t = 10 ms (50 Hz), sine	7820	A <sup>2</sup> s	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz), sine	7210	A <sup>2</sup> s	
T <sub>VJ</sub>		-40...+180	°C	
T <sub>VJM</sub>		180	°C	
T <sub>stg</sub>		-40...+180	°C	
M <sub>d</sub>	Mounting torque	2.4-4.5 21-40	Nm lb.in.	
Weight		21	g	

Symbol	Test Conditions	Characteristic Values		
I <sub>R</sub>	T <sub>VJ</sub> = T <sub>VJM</sub> ; V <sub>R</sub> = V <sub>RRM</sub>	≤ 6	mA	
V <sub>F</sub>	I <sub>F</sub> = 150 A; T <sub>VJ</sub> = 25°C	≤ 1.17	V	
V <sub>TO</sub>	For power-loss calculations only	0.75	V	
r <sub>T</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	2	mΩ	
R <sub>thJC</sub>	DC current	0.5	K/W	
R <sub>thJH</sub>	DC current	0.9	K/W	
d <sub>S</sub>	Creepage distance on surface	4.05	mm	
d <sub>A</sub>	Strike distance through air	3.9	mm	
a	Max. allowable acceleration	100	m/s <sup>2</sup>	

Data according to IEC 60747  
 IXYS reserves the right to change limits, test conditions and dimensions



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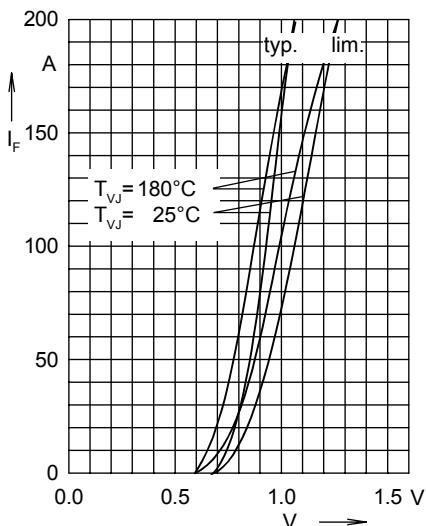


Fig. 1 Forward characteristics

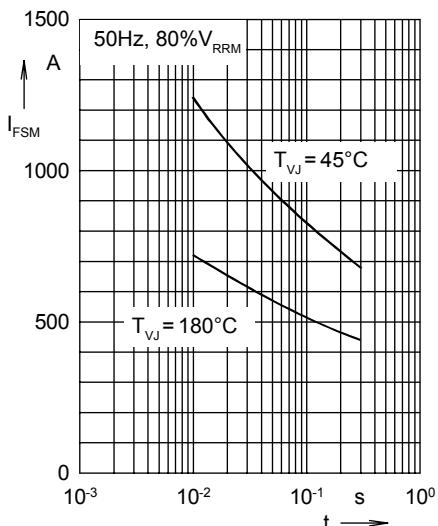


Fig. 2 Surge overload current  
 $I_{FSM}$ : crest value, t: duration

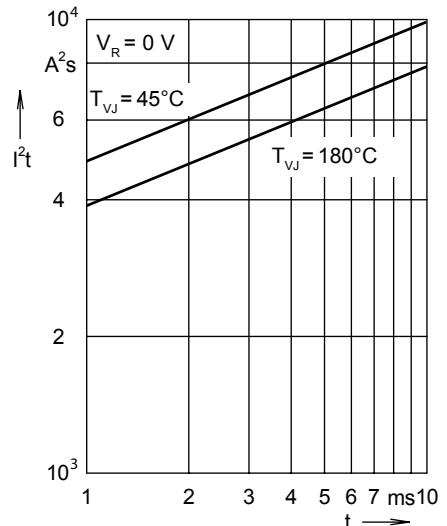


Fig. 3  $I^2t$  versus time (1-10 ms)

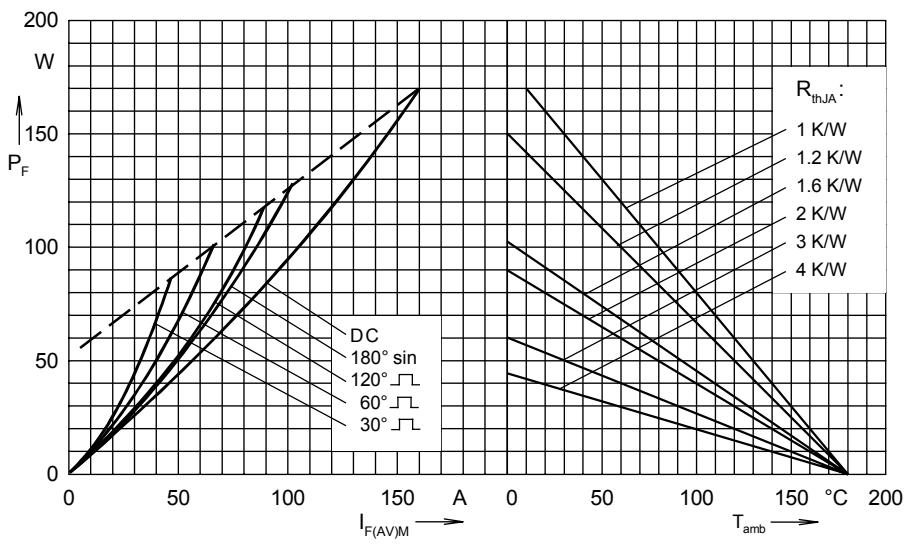


Fig. 4 Power dissipation versus forward current and ambient temperature

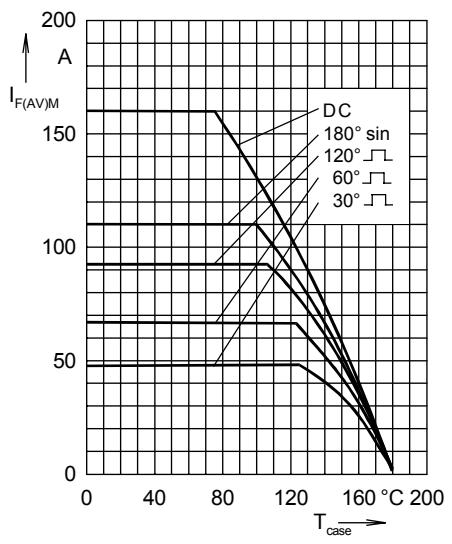


Fig. 5 Max. forward current at case temperature

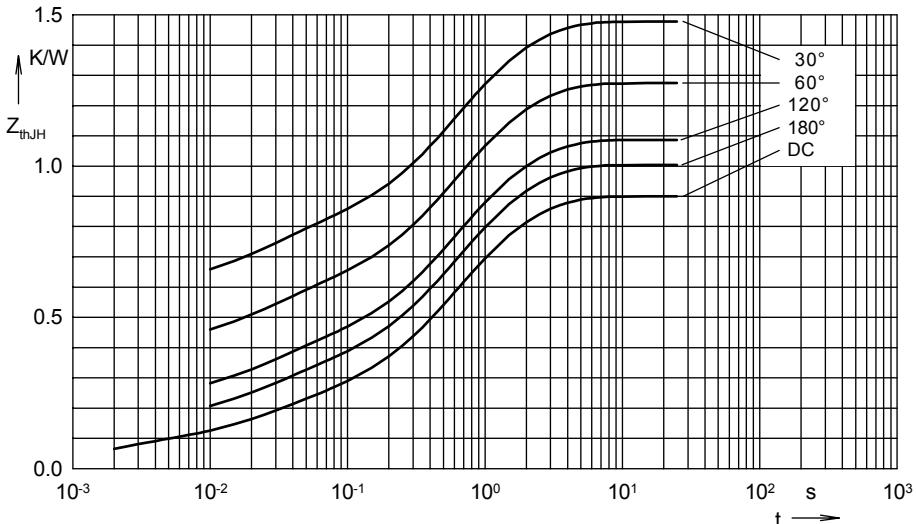


Fig. 6 Transient thermal impedance junction to heatsink

$R_{thJH}$  for various conduction angles d:

d	$R_{thJH}$ (K/W)
DC	0.900
180°	1.028
120°	1.085
60°	1.272
30°	1.476

Constants for  $Z_{thJH}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0731	0.0015
2	0.1234	0.0237
3	0.4035	0.4838
4	0.3000	1.5